

# **Ordering Information**

| Part Number | Top Mark | Package  | Packing Method |
|-------------|----------|----------|----------------|
| KSP55TA     | KSP55    | TO-92 3L | Ammo           |
| KSP56TA     | KSP56    | TO-92 3L | Ammo           |

# **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}$ C unless otherwise noted.

| Symbol             | Parameter                   |            | Value | Unit |  |
|--------------------|-----------------------------|------------|-------|------|--|
| N                  | Collector Deco Valtere      | KSP55      | -60   | V    |  |
| V <sub>CBO</sub> C | Collector-Base Voltage      | KSP56      | -80   |      |  |
| M                  | Collector Emitter Voltage   | KSP55      | -60   | V    |  |
| V <sub>CEO</sub>   | Collector-Emitter Voltage   | KSP56      | -80   | 1    |  |
| V <sub>EBO</sub>   | Emitter-Base Voltage        |            | -4    | V    |  |
| Ι <sub>C</sub>     | Collector Current           |            | -500  | mA   |  |
| P <sub>C</sub>     | Collector Power Dissipation |            | 625   | mW   |  |
| ТJ                 | Junction Temperature        |            | 150   | °C   |  |
| T <sub>STG</sub>   | Storage Temperature         | -55 to 150 | °C    |      |  |

# KSP55 / KSP56 — PNP Epitaxial Silicon Transistor

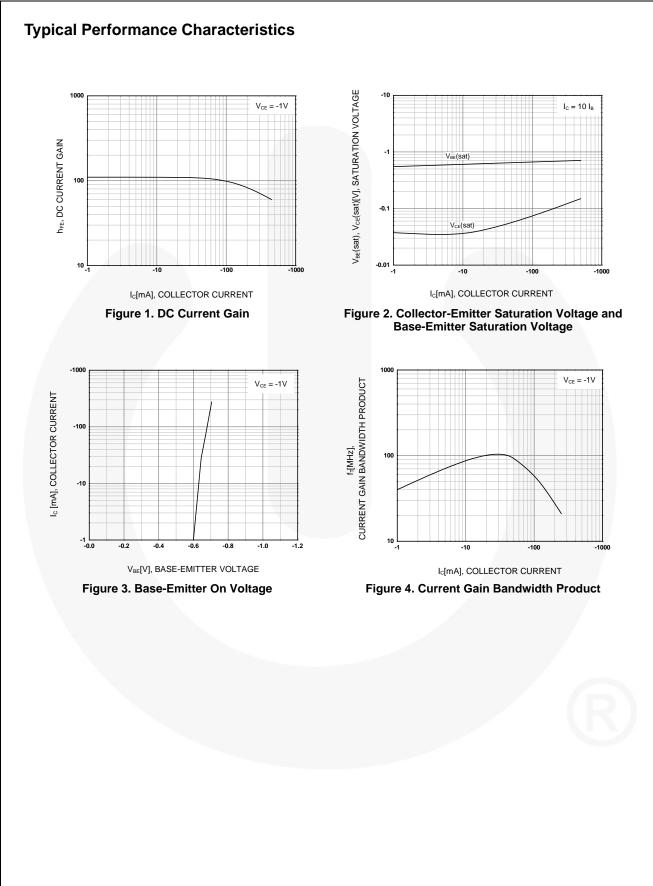
# **Electrical Characteristics**

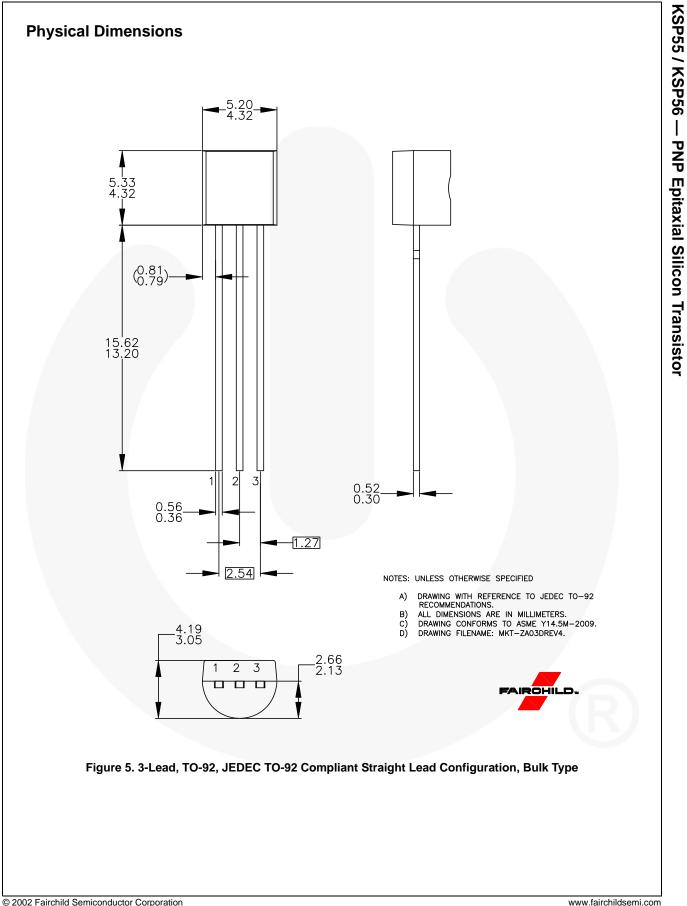
Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

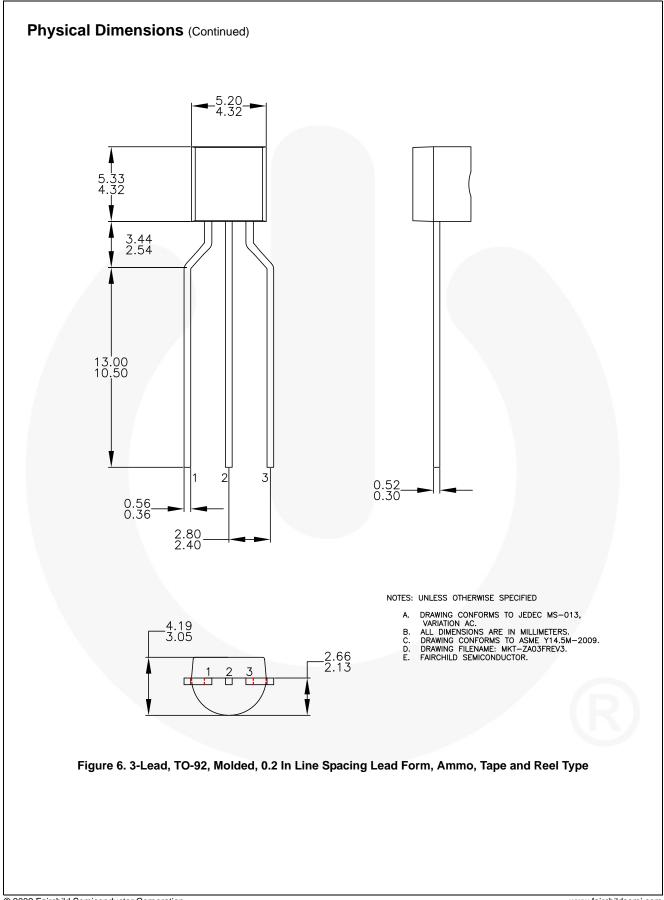
| Symbol                     | Parameter   |       | Parameter Conditions                              | Min. | Max.  | Unit |
|----------------------------|---|-------|---|------|-------|------|
|                            | Collector-Emitter<br>Breakdown Voltage <sup>(1)</sup> | KSP55 | I <sub>C</sub> = -1 mA, I <sub>B</sub> = 0        | -60  |       | v    |
|                            |   | KSP56 |   | -80  |       |      |
| BV <sub>EBO</sub>          | Emitter-Base Breakdown Voltage                        |       | $I_{E} = -100 \ \mu A, \ I_{C} = 0$               | -4   |       | V    |
| I <sub>CBO</sub>           | Collector Cut-Off Current                             | KSP55 | $V_{CB} = -60 \text{ V}, I_E = 0$                 |      | -0.1  |      |
|                            |   | KSP56 | $V_{CB} = -80 \text{ V}, I_{E} = 0$               |      | -0.1  | μΑ   |
| I <sub>CEO</sub>           | Collector Cut-Off Current                             |       | $V_{CE} = -60 \text{ V}, \text{ I}_{B} = 0$       |      | -0.1  | μΑ   |
| h <sub>FE</sub> DC Current | DC Current Gain                                       |       | $V_{CE} = -1 V$ , $I_{C} = -10 mA$                | 50   |       |      |
|                            | Do Current Gain                                       |       | $V_{CE} = -1 V, I_{C} = -100 mA$                  | 50   |       |      |
| V <sub>CE</sub> (sat)      | Collector-Emitter Saturation Voltage                  |       | I <sub>C</sub> = -100 mA, I <sub>B</sub> = -10 mA |      | -0.25 | V    |
| V <sub>BE</sub> (on)       | Base-Emitter On Voltage                               |       | $V_{CE} = -1 V, I_{C} = -100 mA$                  |      | -1.2  | V    |
| f <sub>T</sub>             | Current Gain Bandwidth Product                        |       | $V_{CE} = -2 V, I_{C} = -10 mA,$<br>f = 100 MHz   | 105  |       | MHz  |

# Note:

1. Pulse test: pulse width  $\leq$  300 µs, duty cycle  $\leq$  2%.







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|--------------------------|-----------------------|--|
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| Preliminary              | First Production      | Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild<br>Semiconductor reserves the right to make changes at any time without notice to improve design. |
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Rev. 176